

Fast, Low-Voltage, 2.5Ω, SPST, CMOS Analog Switches

ABSOLUTE MAXIMUM RATINGS

V+, V_{IN} to GND-0.3 to +6V
 COM, NO, NC to GND (Note 1).....-0.3V to (V+ + 0.3V)
 Continuous Current (any terminal).....±50mA
 Peak Current COM, NO, NC
 (pulsed at 1ms 10% duty cycle).....±100mA

Continuous Power Dissipation (T_A = +70°C)
 5-Pin SOT23 (derate 7.1mW/°C above +70°C).....571mW
 6-Pin SOT23 (derate 8.7mW/°C above +70°C).....696mW
 8-Pin μMAX (derate 4.1mW/°C above +70°C)330mW
 Operating Temperature Range-40°C to +85°C
 Storage Temperature Range-65°C to +150°C
 Lead Temperature (soldering, 10s)+300°C

Note 1: Signals on NO, NC, or COM, exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +5V Supply

(V+ = 4.5V to 5.5V, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
COM to NO or NC On-Resistance	R _{ON}	I _{COM} = 10mA, V _{NO} or V _{NC} = 0 to V+, V+ = 4.5V	T _A = +25°C		1.5	2.5	Ω
			T _A = T _{MIN} to T _{MAX}			3	
On-Resistance Flatness (Note 4)	R _{FLAT(ON)}	I _{COM} = 10mA, V _{NO} or V _{NC} = 0 to V+, V+ = 4.5V	T _A = +25°C		0.1	0.4	Ω
			T _A = T _{MIN} to T _{MAX}			0.6	
Off-Leakage Current (NO or NC) (Notes 5, 6)	I _{NO(OFF)} , I _{NC(OFF)}	V _{COM} = 1V, 4.5V; V _{NO} or V _{NC} = 4.5V, 1V; V+ = 5.5V	T _A = +25°C	-0.25	0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	-0.35		0.35	
COM Off-Leakage Current (Notes 5, 6)	I _{COM(OFF)}	V _{COM} = 1V, 4.5V; V _{NO} or V _{NC} = 4.5V, 1V; V+ = 5.5V	T _A = +25°C	-0.25	0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	-0.35		0.35	
COM On-Leakage Current (Notes 5, 6)	I _{COM(ON)}	V+ = 5.5V; V _{COM} = 4.5V, 1V; V _{NO} or V _{NC} = 4.5V, 1V, or floating	T _A = +25°C	-0.25	0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	-0.35		0.35	
LOGIC INPUT							
Input Logic High	V _{IH}			2.4			V
Input Logic Low	V _{IL}					0.8	V
Logic Input Current	I _{IN}	V _{INL} = 0.8V or 2.4V		-0.1	0.005	0.1	μA
SWITCH DYNAMIC CHARACTERISTICS							
Turn-On Time (Note 5)	t _{ON}	V _{NO} , V _{NC} = 3V, R _L = 300Ω, C _L = 35pF, Figure 2	T _A = +25°C		12	15	ns
			T _A = T _{MIN} to T _{MAX}			18	
Turn-Off Time (Note 5)	t _{OFF}	V _{NO} , V _{NC} = 3V, R _L = 300Ω, C _L = 35pF, Figure 2	T _A = +25°C		8	10	ns
			T _A = T _{MIN} to T _{MAX}			12	

Fast, Low-Voltage, 2.5Ω, SPST, CMOS Analog Switches

MAX4645/MAX4646

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

(V₊ = 4.5V to 5.5V, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Charge Injection	Q	V _{GEN} = 2V, C _L = 1.0nF, R _{GEN} = 0, Figure 3 T _A = +25°C		5		pC
NO or NC Capacitance	C _{OFF}	V _{NO} , V _{NC} = GND, f = 1MHz, Figure 5 T _A = +25°C		17		pF
COM Off-Capacitance	C _{COM}	V _{COM} = GND, f = 1MHz, Figure 5 T _A = +25°C		17		pF
COM On-Capacitance	C _{COM}	V _{COM} = V _{NO} , V _{NC} = GND, f = 1MHz, Figure 5 T _A = +25°C		38		pF
Off-Isolation (Note 7)	V _{ISO}	V _{NO} = V _{NC} = 1V _{RMS} , R _L = 50Ω, C _L = 5pF, f = 10MHz, Figure 4 T _A = +25°C		-55		dB
		V _{NO} = V _{NC} = 1V _{RMS} , R _L = 50Ω, C _L = 5pF, f = 1MHz, Figure 4 T _A = +25°C		-75		dB
Total Harmonic Distortion	THD	R _L = 600Ω, 5V _{P-P} , f = 20Hz to 20kHz T _A = +25°C		0.014		%
POWER SUPPLY						
Positive Supply Current	I ₊	V ₊ = 5.5V, V _{IN} = 0 or V ₊ , all channels on or off	T _A = +25°C	0.0001		μA
			T _A = T _{MIN} to T _{MAX}		1.0	

ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V₊ = 2.7V to 3.3V, V_{IH} = 2.0V, V_{IL} = 0.4V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
ANALOG SWITCH						
Input Voltage Range	V _{COM} , V _{NO} , V _{NC}		0		V ₊	V
COM to NO or NC On-Resistance	R _{ON}	I _{COM} = 10mA, V _{NO} or V _{NC} = 0 to V ₊ , V ₊ = 2.7V	T _A = +25°C	2.5	3.5	Ω
			T _A = T _{MIN} to T _{MAX}		4.5	
On-Resistance Flatness (Note 4)	R _{FLAT(ON)}	I _{COM} = 10mA, V _{NO} or V _{NC} = 0 to V ₊ , V ₊ = 2.7V	T _A = +25°C	0.5	0.9	Ω
			T _A = T _{MIN} to T _{MAX}		1	
Off-Leakage Current (NO or NC) (Notes 5, 6)	I _{NO(OFF)} , I _{NC(OFF)}	V _{COM} = 1V, 3V; V _{NO} or V _{NC} = 3V, 1V; V ₊ = 3.3V	T _A = +25°C	-0.25	0.01	nA
			T _A = T _{MIN} to T _{MAX}	-0.35	0.35	
COM Off-Leakage Current (Notes 5, 6)	I _{COM(OFF)}	V _{COM} = 1V, 3V; V _{NO} or V _{NC} = 3V, 1V; V ₊ = 3.3V	T _A = +25°C	-0.25	0.01	nA
			T _A = T _{MIN} to T _{MAX}	-0.35	0.35	
COM On-Leakage Current (Notes 5, 6)	I _{COM(ON)}	V ₊ = 3.3V; V _{COM} = 1V, 3V; V _{NO} or V _{NC} = 1V, 3V or floating	T _A = +25°C	-0.25	0.01	nA
			T _A = T _{MIN} to T _{MAX}	-0.35	0.35	

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ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

(V+ = 2.7V to 3.3V, V_{IH} = 2.0V, V_{IL} = 0.4V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
LOGIC INPUT							
Input Logic High	V _{IH}			2.0			V
Input Logic Low	V _{IL}					0.4	V
Logic Input Current	I _{IN}	V _{INL} = 0.4V or 2.0V		-1	0.005	1	μA
SWITCH DYNAMIC CHARACTERISTICS							
Turn-On Time (Note 5)	t _{ON}	V _{NO} , V _{NC} = 2.0V, R _L = 300Ω, C _L = 35pF, Figure 2	T _A = +25°C	12	15	ns	
			T _A = T _{MIN} to T _{MAX}	20			
Turn-Off Time (Note 5)	t _{OFF}	V _{NO} , V _{NC} = 2.0V, R _L = 300Ω, C _L = 35pF, Figure 2	T _A = +25°C	8	10	ns	
			T _A = T _{MIN} to T _{MAX}	13			
Charge Injection	Q	V _{GEN} = 1.5V, C _L = 1.0nF, R _{GEN} = 0, Figure 3	T _A = +25°C	4	pC		
NO or NC Capacitance	C _{OFF}	V _{NO} , V _{NC} = GND, f = 1MHz, Figure 5	T _A = +25°C	17	pF		
COM Off-Capacitance	C _{COM}	V _{COM} = GND, f = 1MHz, Figure 5	T _A = +25°C	17	pF		
COM On-Capacitance	C _{COM}	V _{COM} = V _{NO} , V _{NC} = GND, f = 1MHz, Figure 5	T _A = +25°C	38	pF		
Off-Isolation (Note 7)	V _{ISO}	V _{NO} = V _{NC} = 1V _{RMS} , R _L = 50Ω, C _L = 5pF, f = 10MHz, Figure 4	T _A = +25°C	-55	dB		
		V _{NO} = V _{NC} = 1V _{RMS} , R _L = 50Ω, C _L = 5pF, f = 1MHz, Figure 4	T _A = +25°C	-75			
POWER SUPPLY							
Positive Supply Current	I ₊	V ₊ = 3.3V, V _{IN} = 0 or V ₊ , all channels on or off	T _A = +25°C	0.0001		μA	
			T _A = T _{MIN} to T _{MAX}	1.0			

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

Note 3: SOT packages are 100% production tested at +25°C. Limits at the maximum rated temperature are guaranteed by correlation.

Note 4: Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.

Note 5: Guaranteed by design.

Note 6: Leakage parameters are 100% tested at +85°C and guaranteed by correlation at +25°C.

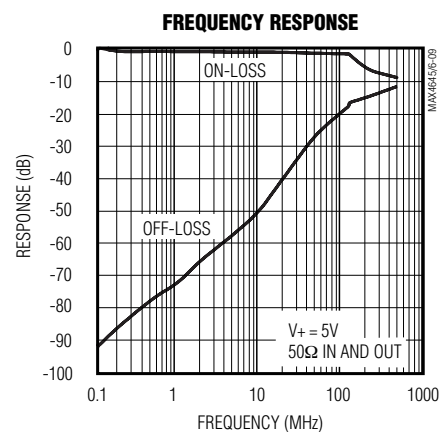
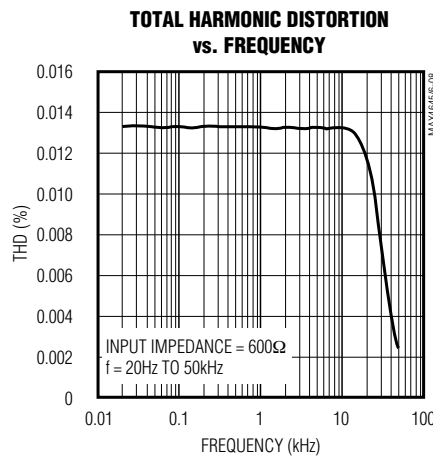
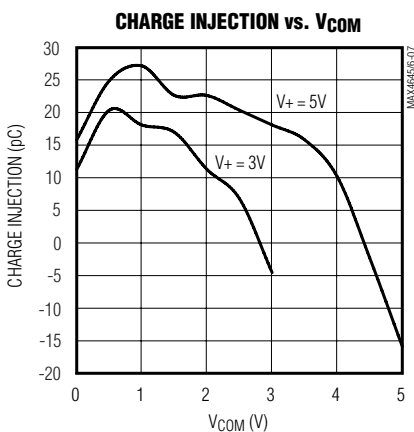
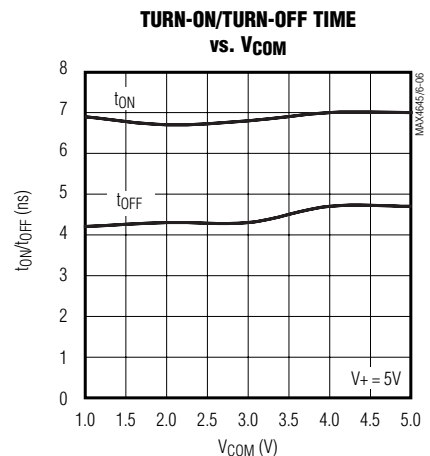
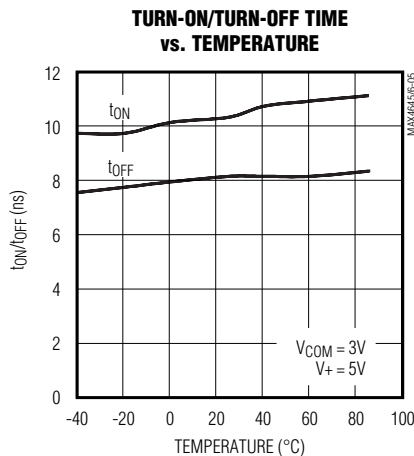
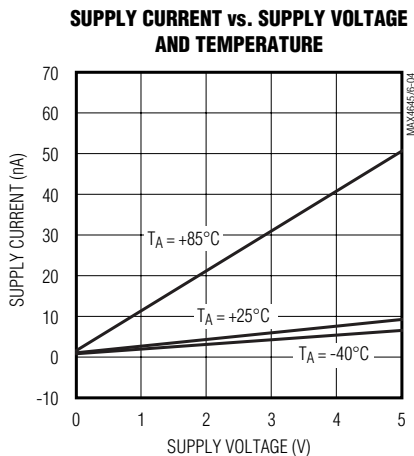
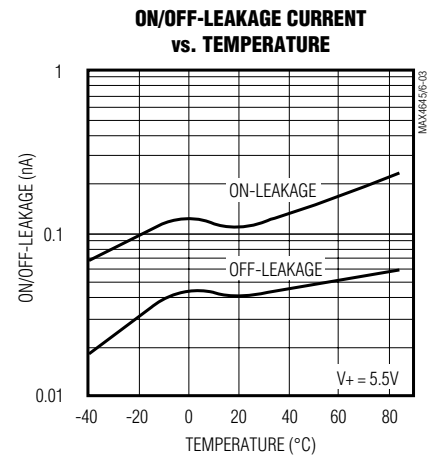
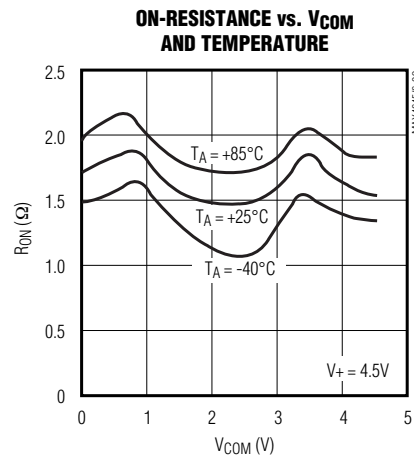
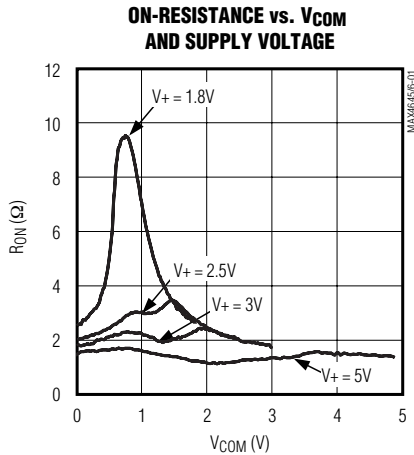
Note 7: Off-Isolation = 20log₁₀(V_{COM} / V_{NO}), V_{COM} = output, V_{NO} = input to off switch.

Fast, Low-Voltage, 2.5Ω , SPST, CMOS Analog Switches

Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

MAX4645/MAX4646



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Pin Description

PIN						NAME	FUNCTION
MAX4645			MAX4646				
SOT23-5	SOT23-6	μMAX	SOT23-5	SOT23-6	μMAX		
1	1	1	1	1	1	COM	Analog Switch Common Terminal
2	2	8	—	—	—	NO	Analog Switch Normally Open Terminal
—	—	—	2	2	8	NC	Analog Switch Normally Closed Terminal
3	3	7	3	3	7	GND	Ground
4	4	6	4	4	6	IN	Logic Control Input
—	5	2, 3, 5	—	5	2, 3, 5	N.C.	No Connection. Not internally connected.
5	6	4	5	6	4	V+	Positive Supply Voltage

Detailed Description

The MAX4645/MAX4646 are low 2.5Ω max on-resistance (at V+ = 5V), low-voltage analog switches that operate from a +1.8V to +5.5V single supply. CMOS switch construction allows processing analog signals that are within the supply voltage range (GND to V+).

Applications Information

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins for overvoltage protection (Figure 1). Adding these diodes reduces the analog signal by one diode drop below V+ and one diode drop above GND, but does not affect the low switch resistance and low leakage characteristics of the device. Device operation is unchanged, and the difference between V+ and GND should not exceed 6V.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise from propagating from the V+ supply to other components. A 0.1μF capacitor, connected from V+ to GND, is adequate for most applications.

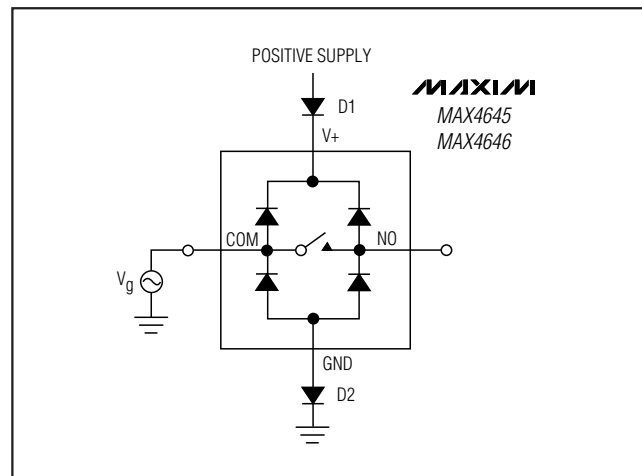


Figure 1. Overvoltage Protection Using Two External Blocking Diodes

Fast, Low-Voltage, 2.5Ω , SPST, CMOS Analog Switches

Test Circuits/Timing Diagrams

MAX4645/MAX4646

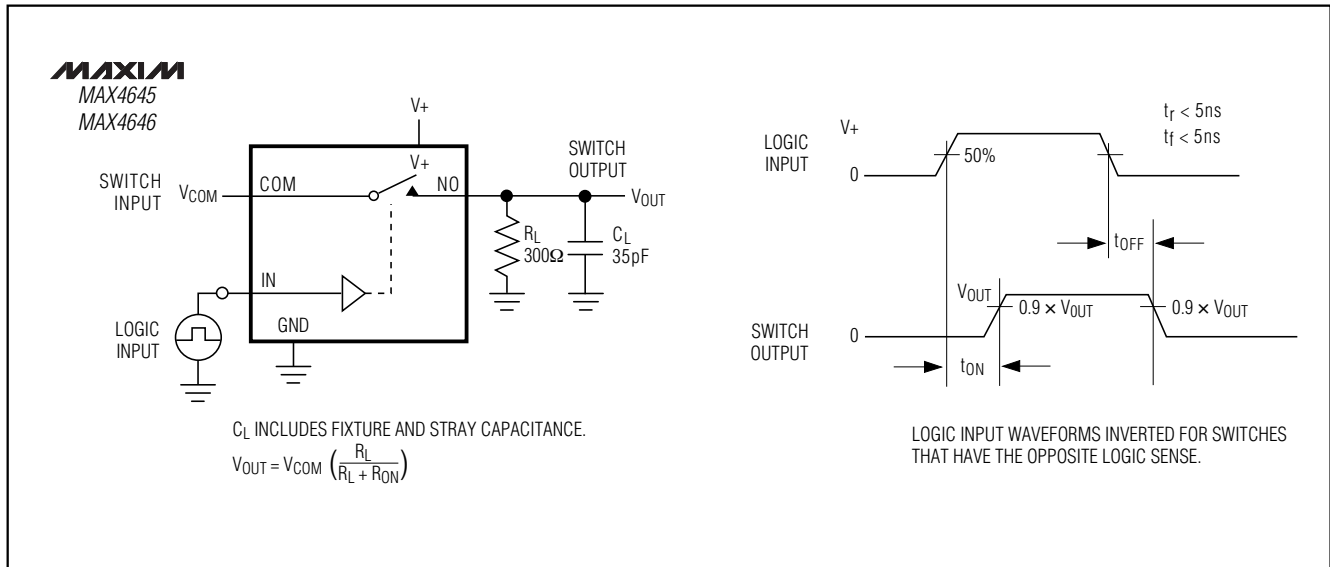


Figure 2. Switching Time

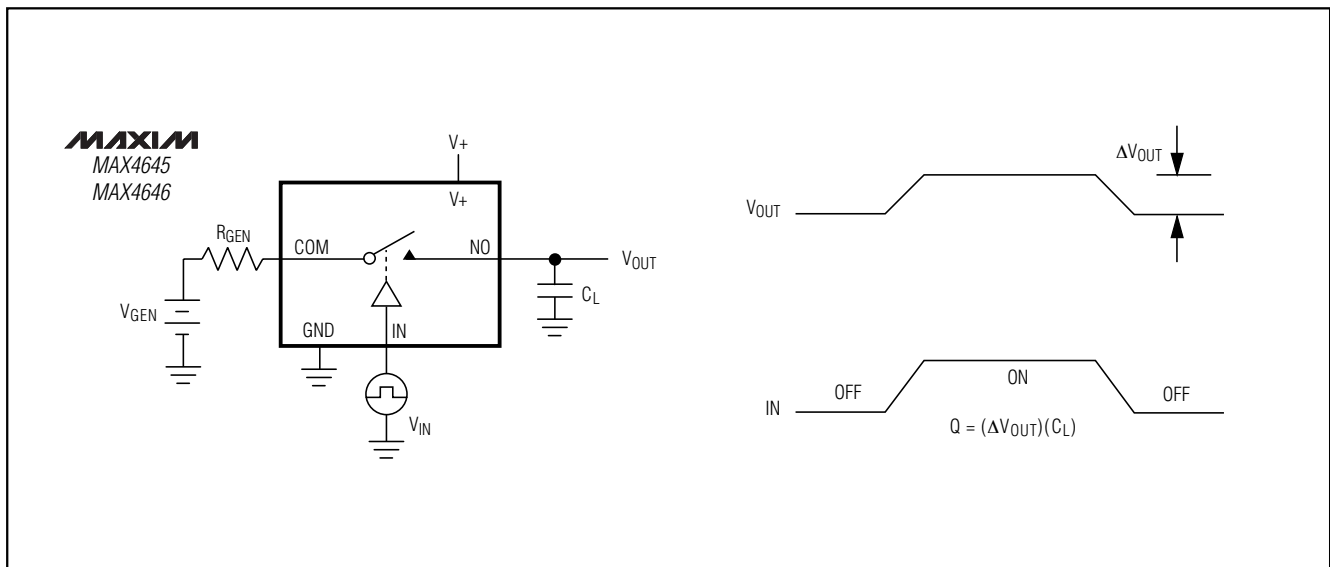


Figure 3. Charge Injection

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Test Circuits/Timing Diagrams (continued)

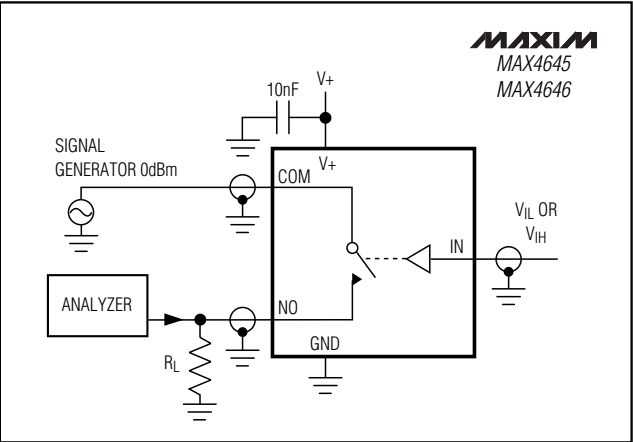


Figure 4. Off-Isolation/On-Channel Bandwidth

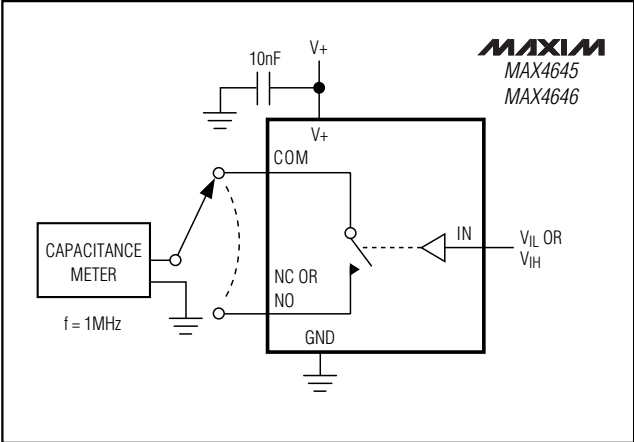
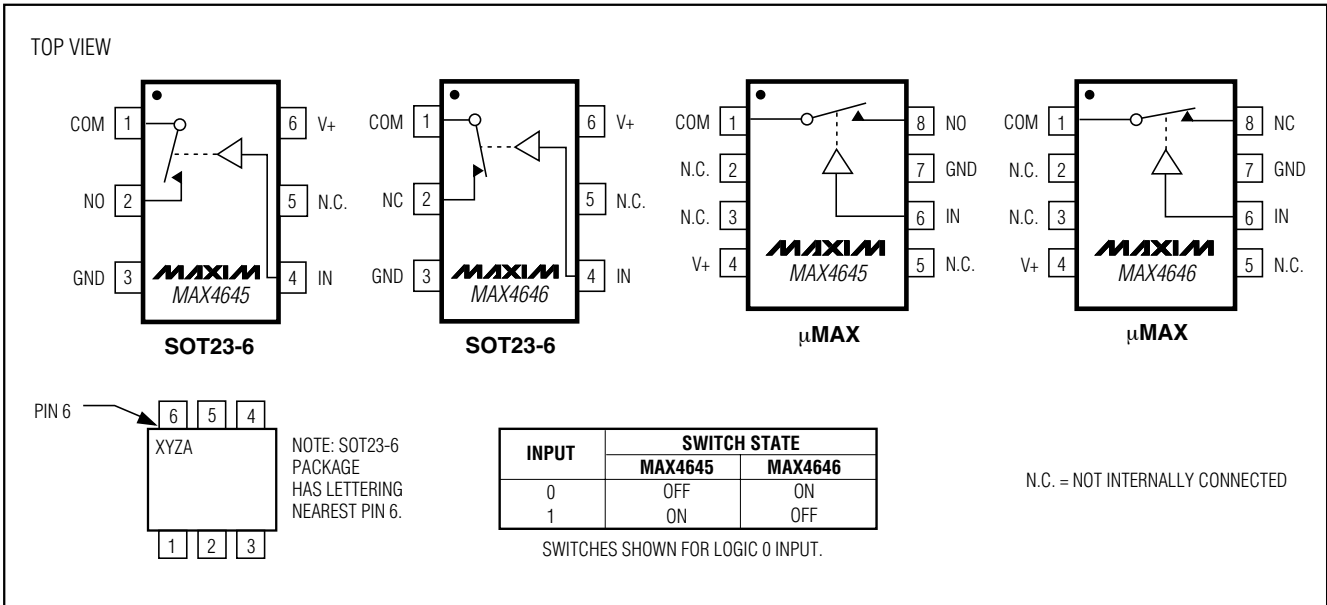


Figure 5. Channel Off/On-Capacitance

Pin Configurations/Functional Diagrams/Truth Tables (continued)



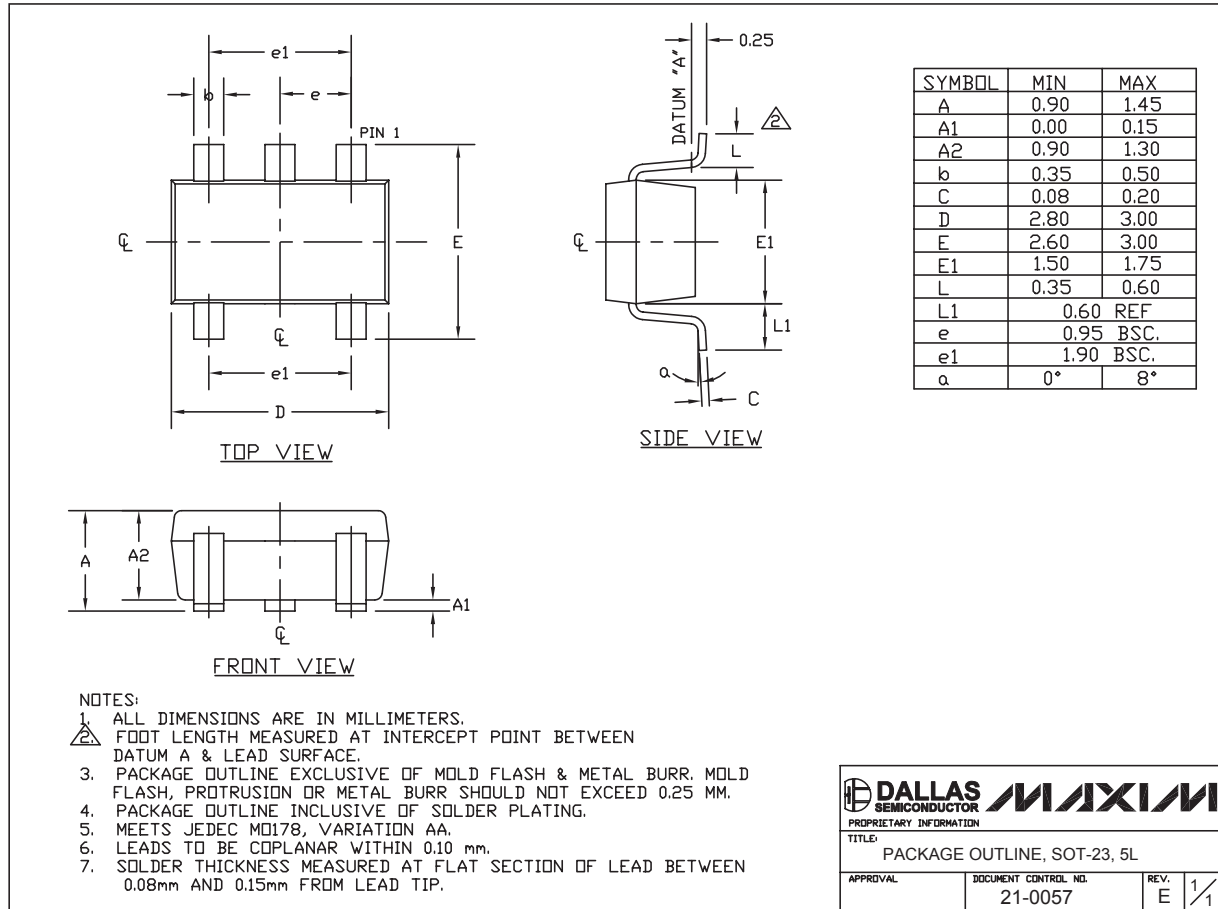
Chip Information

TRANSISTOR COUNT: 50

Fast, Low-Voltage, 2.5Ω, SPST, CMOS Analog Switches

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)



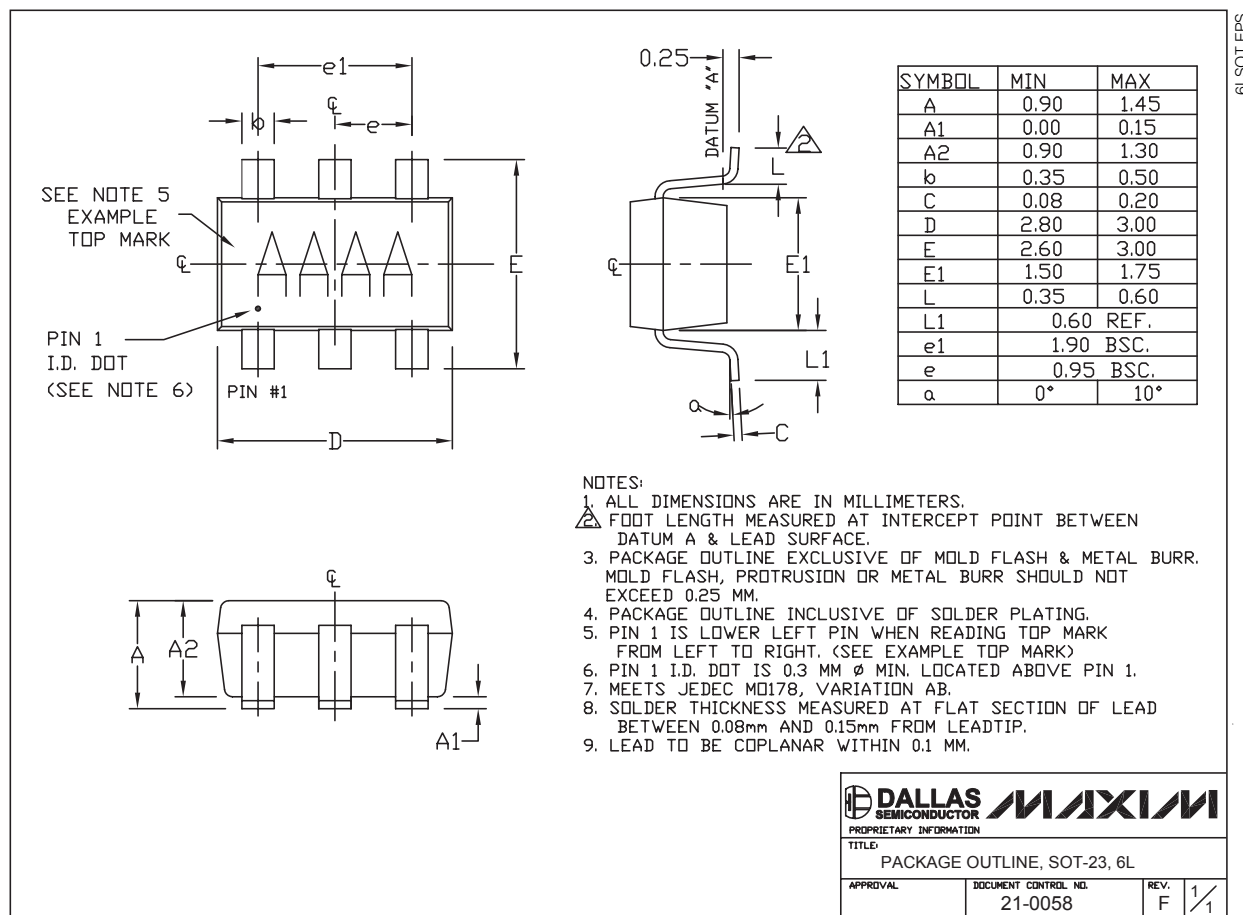
SOT-23 5L.EPS

MAX4645/MAX4646

Fast, Low-Voltage, 2.5Ω , SPST, CMOS Analog Switches

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)



6LSOT.EPS

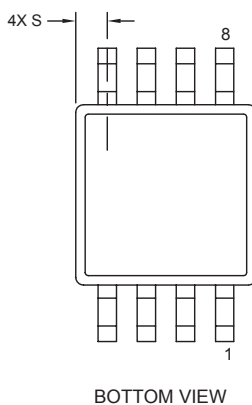
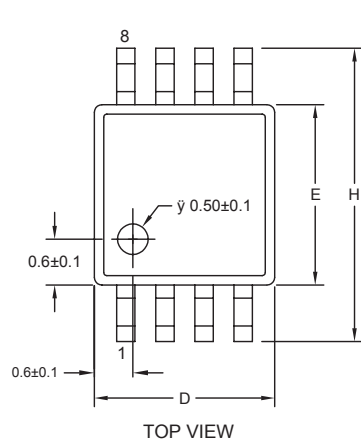
Fast, Low-Voltage, 2.5Ω, SPST, CMOS Analog Switches

Package Information (continued)

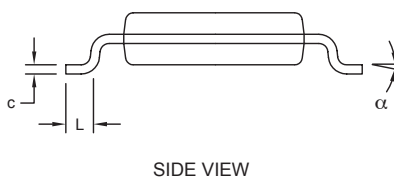
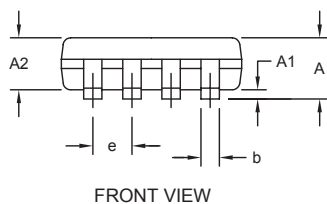
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)

MAX4645/MAX4646

8LUMAXD.EPS



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	-	0.043	-	1.10
A1	0.002	0.006	0.05	0.15
A2	0.030	0.037	0.75	0.95
b	0.010	0.014	0.25	0.36
c	0.005	0.007	0.13	0.18
D	0.116	0.120	2.95	3.05
e	0.0256 BSC		0.65 BSC	
E	0.116	0.120	2.95	3.05
H	0.188	0.198	4.78	5.03
L	0.016	0.026	0.41	0.66
α	0°	6°	0°	6°
S	0.0207 BSC		0.5250 BSC	



NOTES:

1. D&E DO NOT INCLUDE MOLD FLASH.
2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15MM (.006").
3. CONTROLLING DIMENSION: MILLIMETERS.
4. MEETS JEDEC MO-187C-AA.

			
PROPRIETARY INFORMATION			
TITLE:			
PACKAGE OUTLINE, 8L uMAX/uSOP			
APPROVAL	DOCUMENT CONTROL NO.	REV.	1/1
	21-0036	J	

Note: The MAX4645/MAX4646 do not have an exposed paddle.

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